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**Amendments to the Claims:**

The following claims will replace all prior versions of the claims in this application (in the unlikely event that no claims follow herein, the previously pending claims will remain):

1. (Currently Amended) An electro-absorption optical modulator comprising:  
an absorption layer;  
upper and lower clad layers formed on upper and lower portions of the absorption layer, respectively; and  
electrodes for applying an electric field to the absorption layer,  
wherein the absorption layer has a vertical combination of at least two quantum wells having a width different from each other;

wherein the at least two quantum wells include a first quantum well having a narrow width and a second quantum well having a wide width, the absorption layer having at least one of the first quantum well and at least one of the second quantum well at a number ratio of  $m > n$ , where  $m$  is the number of first quantum wells and  $n$  is the number of second quantum wells; and

wherein an  $\alpha$  value of the first quantum well is larger than an  $\alpha$  value of the second quantum well.

2. (Cancelled)

3. (Currently Amended) The electro-absorption optical modulator as claimed in claim 2 1, wherein ~~an~~ the  $\alpha$  value of the first quantum well is larger than that of ~~an~~ the  $\alpha$  value of the second quantum well in the following equation:

$$P_{out} = P_{in} \exp(- (V/V_0)^\alpha)$$

4. (Previously Presented) The electro-absorption optical modulator as claimed in claim 3, wherein the  $\alpha$  value of the first quantum well is larger than that of the second quantum well by at least 0.5.

5. (Previously Presented) The electro-absorption optical modulator as claimed in claim 1, wherein the absorption layer includes a compound semiconductor base material.